LM4040
Precision micropower shunt voltage references

Description

The LM4040 is a family of bandgap circuits designed to achieve precision micro-power voltage references of 2.5V, 3.0V and 5.0V. The devices are available in 0.2% B-grade, 0.5% C-grade and 1% D-grade initial tolerances.

They are available in small outline SOT23 and SC75 surface mount package which are ideal for applications where space saving is important.

Excellent performance is maintained over the 60µA to 15mA operating current range with a typical temperature coefficient of only 20ppm/°C. The device has been designed to be highly tolerant of capacitive loads so maintaining excellent stability.

This device offers a pin for pin compatible alternative to the LM4040 voltage reference. The LM4040 is also available with AEC-Q100 approval; see LM4040Q datasheet

Features

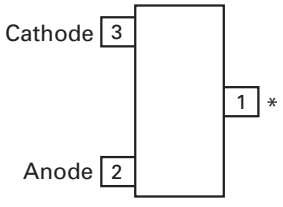
- Small packages: SOT23 & SC75
- No output capacitor required
- Output voltage tolerance
  - LM4040B ±0.2% at 25°C
  - LM4040C ±0.5% at 25°C
  - LM4040D ±1% at 25°C
- Low output noise (10Hz to 10kHz)..... 45µV_{RMS}
- Wide operating current range 60µA to 15mA
- Extended temperature range -40°C to +125°C
- Low temperature coefficient 100 ppm/°C (max)

Applications

- Battery powered equipment
- Precision power supplies
- Portable instrumentation
- Portable communications devices
- Notebook and palmtop computers
- Data acquisition systems

Pinout information

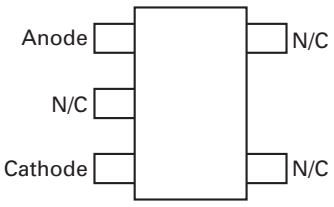
LM4040 F (SOT23)



Top view

* Pin 1 must be left floating or connected to pin 2

LM4040 H5 (SC70)



Top view

* Pin 1 must be left floating or connected to pin 2

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Ordering information

25ºC Tol	Voltage (V)	Order Code	Package	Part mark	Status	Reel Size	Tape Width	Quantity per reel
0.2%	2.5	LM4040B25FTA	SOT23	R2B	Active	7", 180mm	8mm	3000
		LM4040B25H5TA	SC75	R2B	Active	7", 180mm	8mm	3000
	3.0	LM4040B30FTA	SOT23	R3B	Active	7", 180mm	8mm	3000
		LM4040B30H5TA	SC75	R3B	Active	7", 180mm	8mm	3000
	5.0	LM4040B50FTA	SOT23	R5B	Active	7", 180mm	8mm	3000
		LM4040B50H5TA	SC75	R5B	Active	7", 180mm	8mm	3000
0.5%	2.5	LM4040C25FTA	SOT23	R2C	Active	7", 180mm	8mm	3000
		LM4040C25H5TA	SC75	R2C	Active	7", 180mm	8mm	3000
	3.0	LM4040C30FTA	SOT23	R3C	Active	7", 180mm	8mm	3000
		LM4040C30H5TA	SC75	R3C	Active	7", 180mm	8mm	3000
	5.0	LM4040C50FTA	SOT23	R5C	Active	7", 180mm	8mm	3000
		LM4040C50H5TA	SC75	R5C	Active	7", 180mm	8mm	3000
1%	2.5	LM4040D25FTA	SOT23	R2D	Active	7", 180mm	8mm	3000
		LM4040D25H5TA	SC75	R2D	Active	7", 180mm	8mm	3000
	3.0	LM4040D30FTA	SOT23	R3D	Active	7", 180mm	8mm	3000
		LM4040D30H5TA	SC75	R3D	Active	7", 180mm	8mm	3000
	5.0	LM4040D50FTA	SOT23	R5D	Active	7", 180mm	8mm	3000
		LM4040D50H5TA	SC75	R5D	Active	7", 180mm	8mm	3000

Absolute maximum ratings

Continuous reverse current (I_R) 20mA

Continuous forward current (I_{REF}) 10mA

Operating junction temperature ..... -40°C to 150°C

Storage temperature ..... -55°C to 150°C

Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.

Unless otherwise stated voltages specified are relative to the ANODE pin.

Package thermal data

Package	Θ_{JA}	P_{DIS} T_{amb} =25°C, T_J = 150°C
SOT23	380°C/W	330mW
SC75	380°C/W	330mW

Recommended operating conditions

	Min.	Max.	Units
Reverse current	0.06	15	mA
Operating ambient temperature range	-40	125	°C

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Electrical characteristics

Over recommended operating conditions, T_{amb} = 25°C, unless otherwise stated.

Symbol	Parameter	Conditions		Typ.	LM404 B limits	LM4040 C limits	LM4040 D limits	Units
			T_{amb}					
V_{REF}	Reverse breakdown voltage	I_R = 100µA	25°C	2.5				V
	Reverse breakdown voltage tolerance	I_R = 100µA	25°C		±5	±12	±25	mV
			-40 to 85°C		±21	±29	±49	
			-40 to 125°C		±30	±38	±63	
I_{RMIN}	Minimum operating current		25°C	45	60	60	65	µA
			-40 to 85°C		65	65	70	
			-40 to 125°C		68	68	73	
$\Delta V_R/\Delta T$	Average reverse breakdown voltage temperature coefficient	I_R = 10mA	-40 to 125°C	±20				ppm/°C
		I_R = 1mA,		±15	100	±100	±150	
		I_R = 100µA		±15				
$\Delta V_R/\Delta I_R$	Reverse breakdown change with current	$I_{RMIN} < I_R$ < 1mA	25°C	0.3	0.8	0.8	1.0	mV
			-40 to 85°C		1.0	1.0	1.2	
			-40 to 125°C		1.0	1.0	1.2	
		1mA < I_R < 15 mA	25°C	2.5	6.0	6.0	8.0	
			-40 to 85°C		8.0	8.0	10.0	
			-40 to 125°C		8.0	8.0	10.0	
Z_R	Dynamic output impedance	I_R = 1mA, f = 120Hz $I_{AC} = 0.1I_R$		0.3	0.8	0.9	1.1	Ω
e_n	Noise voltage	I_R = 100µA 10Hz < f < 10kHz		35				μV_{RMS}
ΔV_R	Long term stability (non cumulative)	t = 1000Hrs I_R = 100µA		120				ppm
V_{HYST}	Thermal hysteresis	ΔT = -40°C to +125°C		0.08				%

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Electrical characteristics

Over recommended operating conditions, T_{amb} = 25°C, unless otherwise stated

Symbol	Parameter	Conditions		Typ.	LM404 B limits	LM4040 C limits	LM4040 D limits	Units
			T_{amb}					
V_{REF}	Reverse breakdown voltage	I_R = 100µA	25°C	3.0				V
	Reverse breakdown voltage tolerance	I_R = 100µA	25°C		±6	±15	±30	mV
			-40 to 85°C		±26	±34	±59	
			-40 to 125°C		TBD	±45	±75	
I_{RMIN}	Minimum operating current		25°C	47	62	62	67	µA
			-40 to 85°C		67	67	72	
			-40 to 125°C		70	70	75	
$\Delta V_R/\Delta T$	Average reverse breakdown voltage temperature coefficient	I_R = 10mA	-40 to 125°C	±20				ppm/°C
		I_R = 1mA,		±15	100	±100	±150	
		I_R = 100µA		±15				
$\Delta V_R/\Delta I_R$	Reverse breakdown change with current	$I_{RMIN} < I_R < 1mA$	25°C	0.4	0.8	0.8	1.1	mV
			-40 to 85°C		1.1	1.1	1.3	
			-40 to 125°C		1.1	1.1	1.3	
		1mA < I_R < 15 mA	25°C	2.7	6.0	6.0	8.0	
			-40 to 85°C		9.0	9.0	11.0	
			-40 to 125°C		9.0	9.0	11.0	
Z_R	Dynamic output impedance	I_R = 1mA, f = 120Hz $I_{AC} = 0.1I_R$		0.4	0.9	0.9	1.2	Ω
e_n	Noise voltage	I_R = 100µA 10Hz < f < 10kHz		35				μV_{RMS}
ΔV_R	Long term stability (non cumulative)	t = 1000Hrs I_R = 100µA		120				ppm
V_{HYST}	Thermal hysteresis	ΔT = -40°C to +125°C		0.08				%

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Electrical characteristics

Over recommended operating conditions, T_{amb} = 25°C, unless otherwise stated.

Symbol	Parameter	Conditions		Typ.	LM404 B limits	LM4040 C limits	LM4040 D limits	Units
			T_{amb}					
V_{REF}	Reverse breakdown voltage	I_R = 100µA	25°C	5.0	5.0			V
	Reverse breakdown voltage tolerance	I_R = 100µA	25°C		±10	±25	±50	mV
			-40 to 85°C		±43	±58	±99	
			-40 to 125°C		±60	±75	±125	
I_{RMIN}	Minimum operating current		25°C	54	74	74	79	µA
			-40 to 85°C		80	80	85	
			-40 to 125°C		83	83	88	
$\Delta V_R/\Delta T$	Average reverse breakdown voltage temperature coefficient	I_R = 10mA	-40 to 125°C	±30				ppm/°C
		I_R = 1mA,		±20	100	±100	±150	
		I_R = 100µA		±20				
$\Delta V_R/\Delta I_R$	Reverse breakdown change with current	$I_{RMIN} < I_R$ < 1mA	25°C	0.5	1.0	1.0	1.3	mV
			-40 to 85°C		1.4	1.4	1.8	
			-40 to 125°C		1.4	1.4	1.8	
		1mA < I_R < 15 mA	25°C	3.5	8.0	8.0	10.0	
			-40 to 85°C		12.0	12.0	15.0	
			-40 to 125°C		12.0	12.0	15.0	
Z_R	Dynamic output impedance	I_R = 1mA, f = 120Hz $I_{AC} = 0.1I_R$		0.5	1.1	1.1	1.5	Ω
e_n	Noise voltage	I_R = 100µA 10Hz < f < 10kHz		80				μV_{RMS}
ΔV_R	Long term stability (non cumulative)	t = 1000Hrs I_R = 100µA		120				ppm
V_{HYST}	Thermal hysteresis	ΔT = -40°C to +125°C		0.08				%

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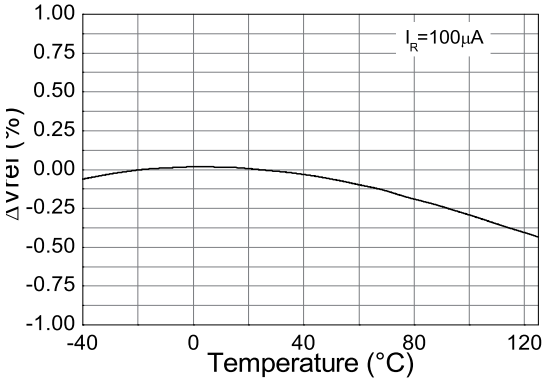
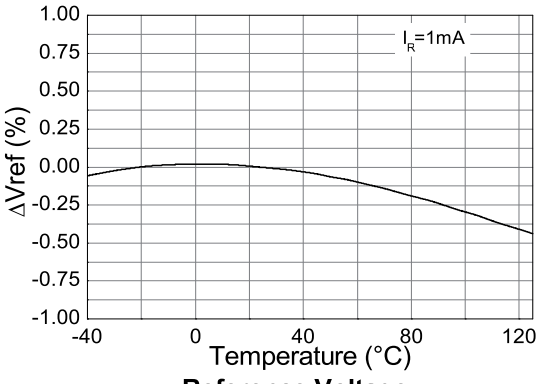
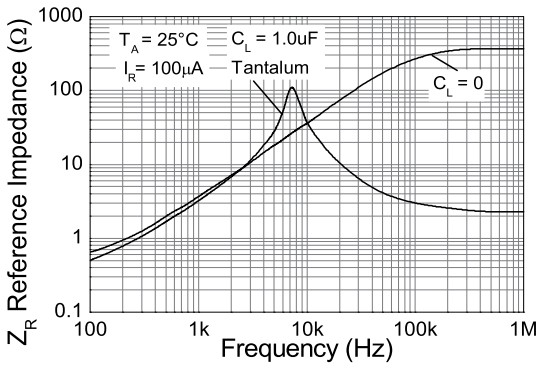
LM4040-2.5 Typical Characteristics



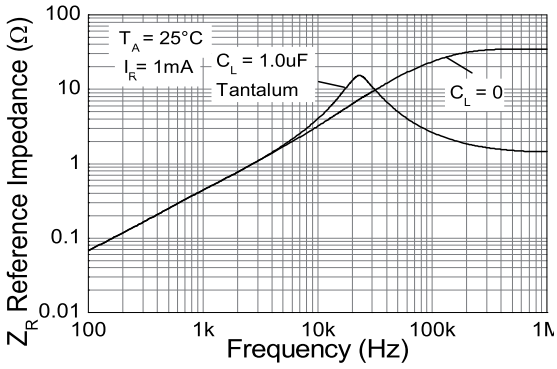
Reference Voltage Temperature Coefficient



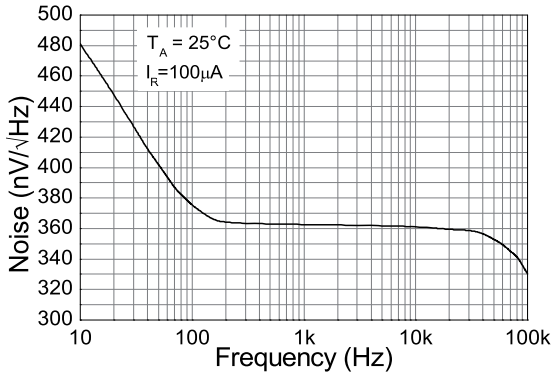
Reference Voltage Temperature Coefficient



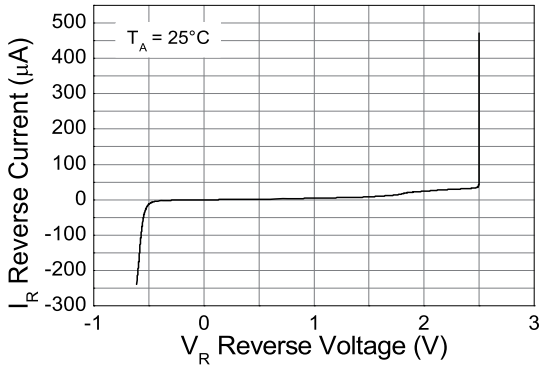
Reference Impedance vs Frequency



Reference Impedance vs Frequency



Noise Voltage vs Frequency



Reverse Current vs Voltage

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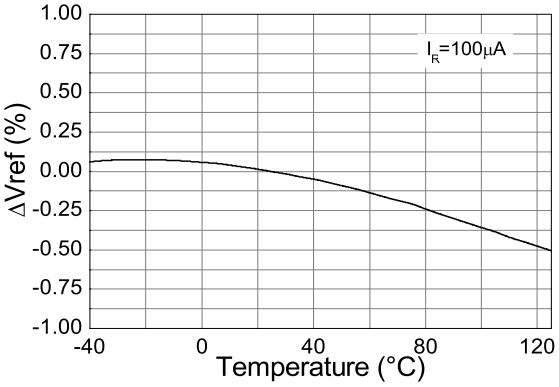
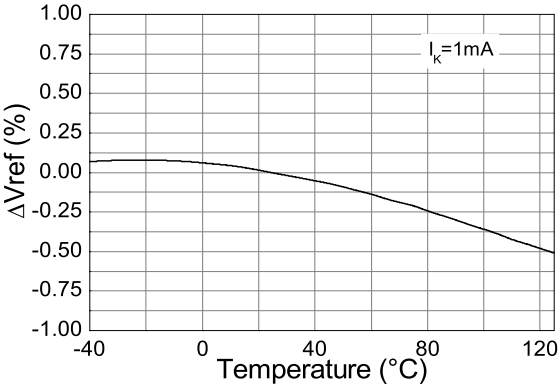
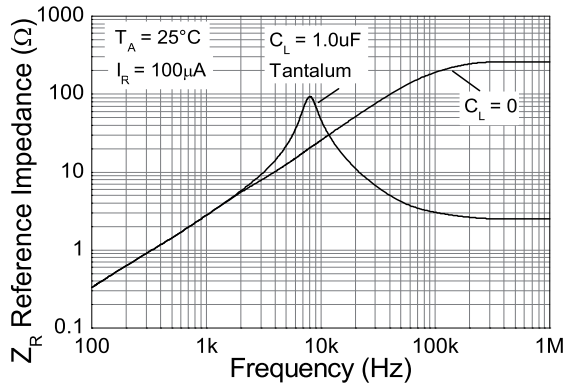
LM4040-3.0 Typical characteristics



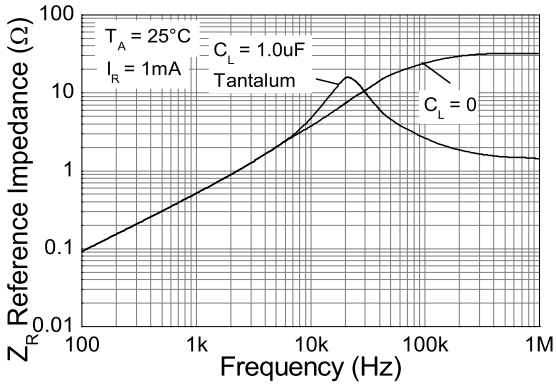
Reference Voltage Temperature Coefficient



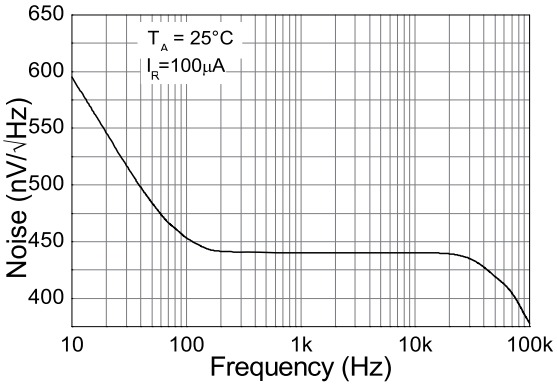
Reference Voltage Temperature Coefficient



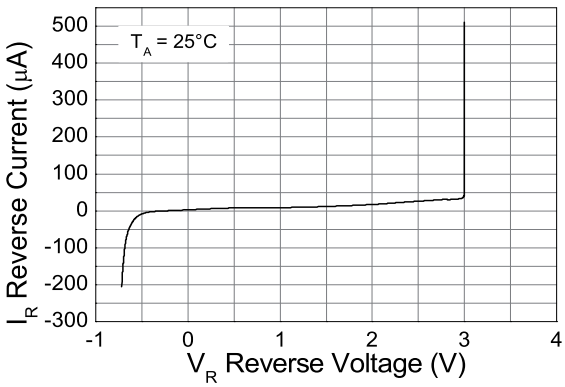
Reference Impedance vs Frequency



Reference Impedance vs Frequency



Noise Voltage vs Frequency



Reverse Current vs Voltage

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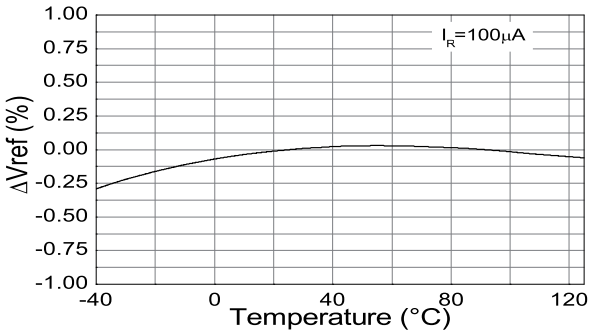
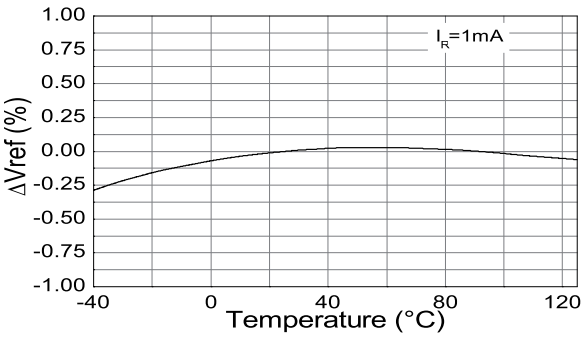
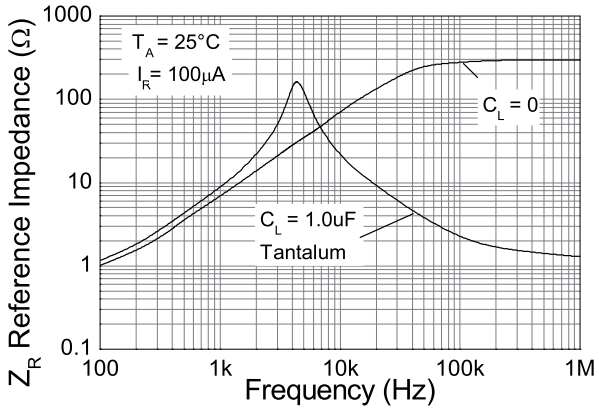
LM4040-5.0 Typical characteristics



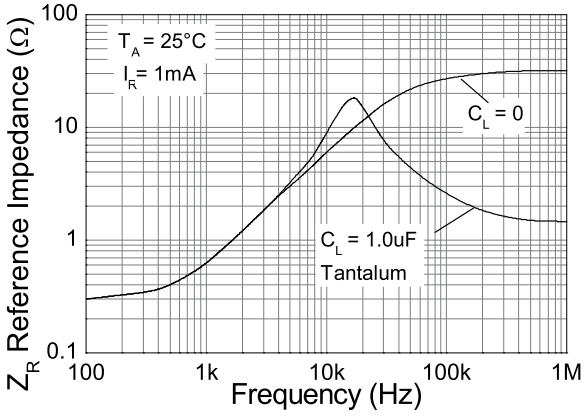
Reference Voltage Temperature Coefficient



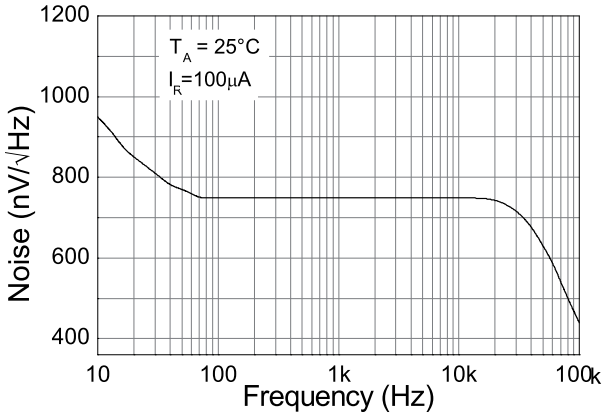
Reference Voltage Temperature Coefficient



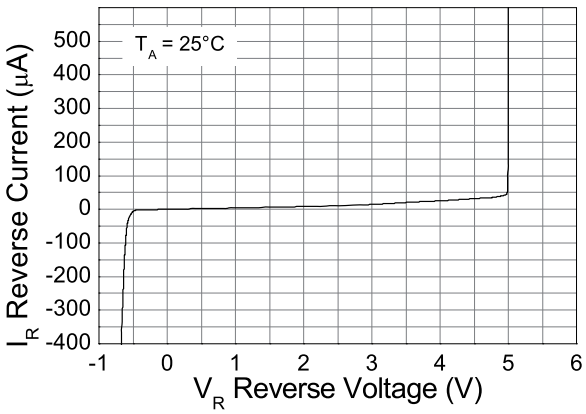
Reference Impedance vs Frequency



Reference Impedance vs Frequency



Noise Voltage vs Frequency



Reverse Current vs Voltage

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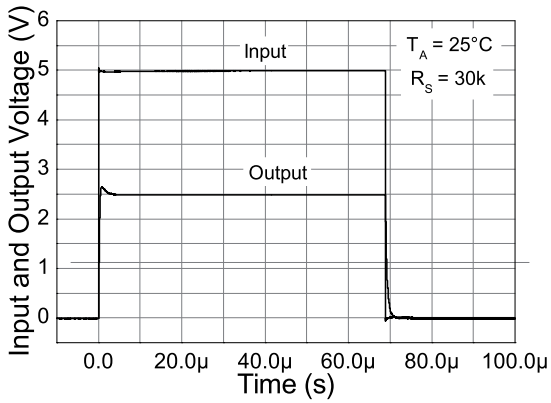
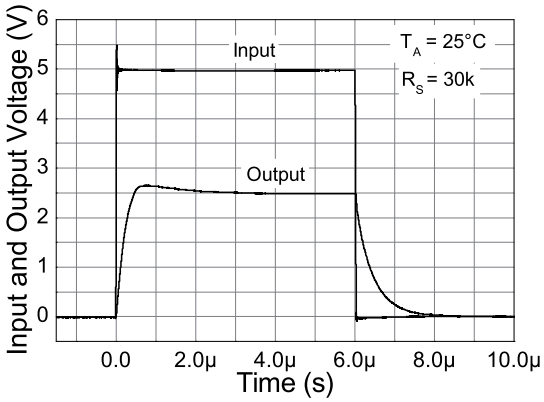
LM4040 - 2.5, 3.0 and 5.0 Start up characteristics

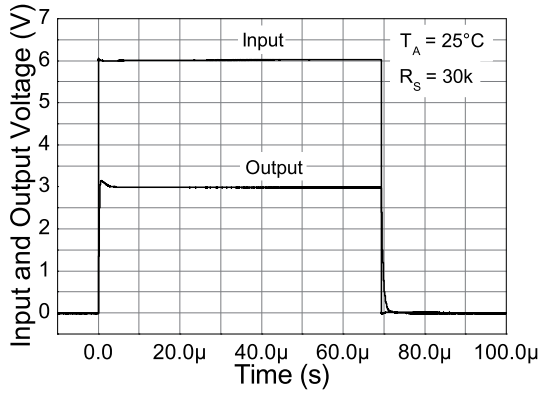


Long Pulse Response

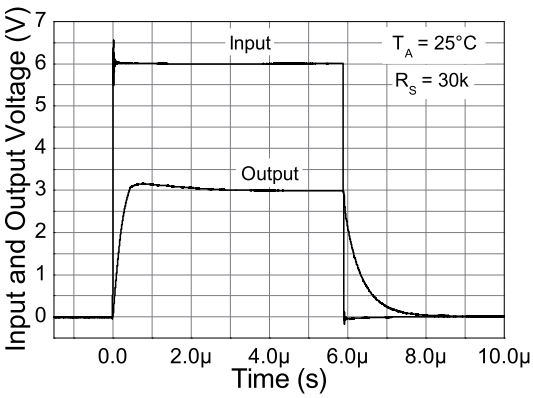


Short Pulse Response

LM4040-3.0

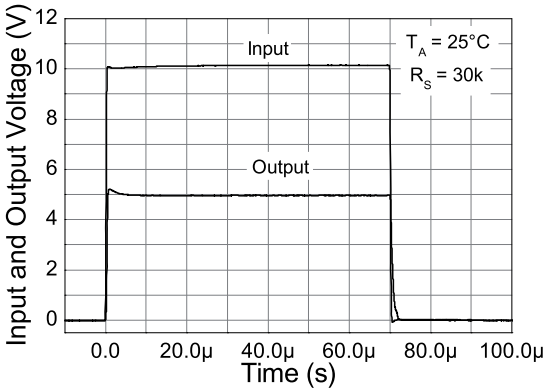


Long Pulse Response

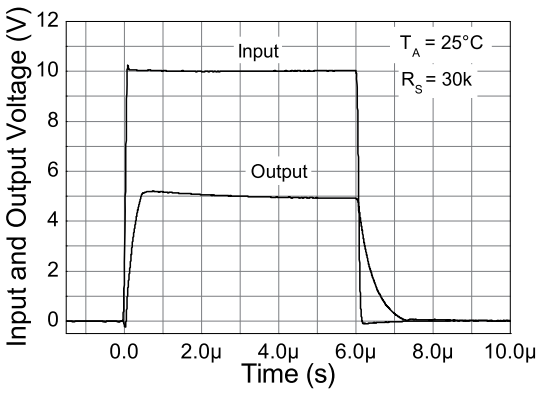


Short Pulse Response

LM4040-5.0



Long Pulse Response



Short Pulse Response

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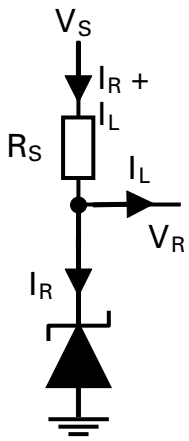
Application information



In a conventional shunt regulator application, an external series resistor (R_S) is connected between the supply voltage, V_S, and the LM4040

R_S determines the current that flows through the load (I_L) and the LM4040 (I_R). Since load current and supply voltage may vary, R_S should be small enough to supply at least the minimum acceptable I_R to the LM4040 even when the supply voltage is at its minimum and the load current is at its maximum value. When the supply voltage is at its maximum and I_L is at its minimum, R_S should be large enough so that the current flowing through the LM4040 is less than 15 mA.

R_S is determined by the supply voltage, (V_S), the load and operating current, (I_L and I_R), and the LM4040's reverse breakdown voltage, V_R.

$$R_S = \frac{V_S - V_R}{I_L + I_R}$$

Printed circuit board layout considerations

LM4040s in the SOT23 package have the die attached to pin 1, which results in an electrical contact between pin 2 and pin 3. Therefore, pin 1 of the SOT-23 package must be left floating or connected to pin 2.

LM4040s in the SC75 package have the die attached to pin 2, which results in an electrical contact between pin 2 and pin 1. Therefore, pin 2 must be left floating or connected to pin1.

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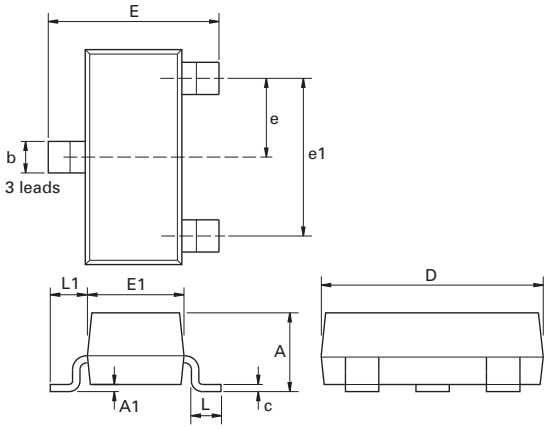
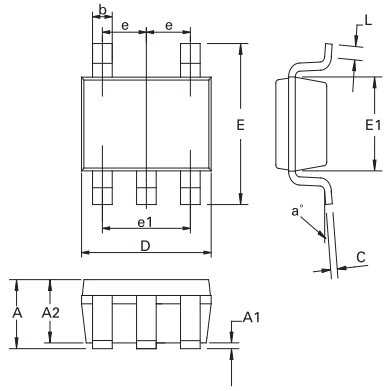
Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
C	0.085	0.120	0.003	0.008	L	0.25	0.62	0.018	0.024
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
e	0.95 NOM		0.0375 NOM		-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Package outline SC-70-5



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	0.80	1.10	0.0315	0.0433	E	2.10 BSC		0.0826 BSC	
A1	-	0.10	-	0.0039	E1	1.25 BSC		0.0492 BSC	
A2	0.80	1.00	0.0315	0.0394	e	0.65 BSC		0.0255 BSC	
b	0.15	0.30	0.006	0.0118	e1	1.30 BSC		0.0511 BSC	
C	0.08	0.25	0.0031	0.0098	L	0.26	0.46	0.0102	0.0181
D	2.00 BSC		0.0787 BSC		a°	0	8	0	8

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or

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